

GaAs INFRARED EMITTING DIODE

LED55B LED55C LED56

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)								
Parameter	Symbol	Rating	Unit					
Operating Temperature	T _{OPR}	-65 to +125	°C					
Storage Temperature	T _{STG}	-65 to +150	°C					
Soldering Temperature (Iron)(3,4,5 and 6)	T _{SOL-I}	240 for 5 sec	°C					
Soldering Temperature (Flow)(3,4 and 6)	T _{SOL-F}	260 for 10 sec	°C					
Continuous Forward Current	I _F	100	mA					
Forward Current (pw, 1µs; 200Hz)	I _F	10	A					
Reverse Voltage	V _R	3	V					
Power Dissipation (T _A = 25°C) ⁽¹⁾	P _D	170	mW					
Power Dissipation (T _C = 25°C) ⁽²⁾	P _D	1.3	W					

NOTE

- 1. Derate power dissipation linearly 1.70 mW/°C above 25°C ambient.
- 2. Derate power dissipation linearly 13.0 mW/°C above 25°C case.
- 3. RMA flux is recommended.
- 4. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
- 6. As long as leads are not under any stress or spring tension
- 7. Total power output, P_0 , is the total power radiated by the device into a solid angle of 2 π steradians.

ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C) (All measurements made under pulse conditions)								
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS		
Peak Emission Wavelength	I _F = 100 mA	λ_{P}	_	940	_	nm		
Emission Angle at 1/2 Power	I _F = 100 mA	θ	_	±8	_	Deg.		
Forward Voltage	I _F = 100 mA	V_{F}	_	_	1.7	V		
Reverse Leakage Current	V _R = 3 V	I _R	_	_	10	μA		
Total Power LED55B(7)	I _F = 100 mA	Po	3.5	_	_	mW		
Total Power LED55C(7)	I _F = 100 mA	Po	5.4	_	_	mW		
Total Power LED56(7)	I _F = 100 mA	Po	1.5	_	_	mW		
Rise Time 0-90% of output		t _r	_	1.0	_	μs		
Fall Time 100-10% of output		t _f	_	1.0	_	μs		

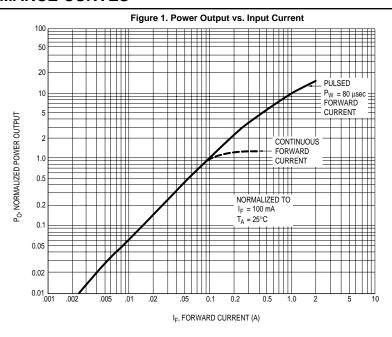
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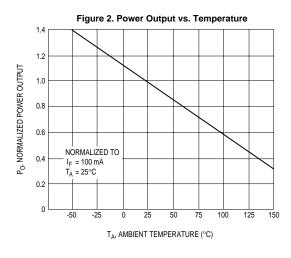
LED55B

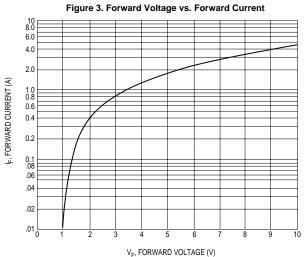
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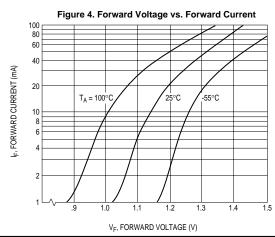
LED56

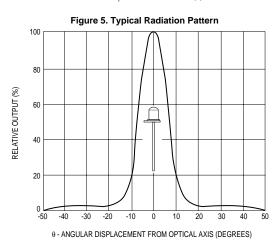
TYPICAL PERFORMANCE CURVES













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